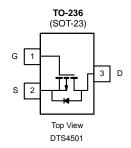


## DTS4501 www.din-tek.jp

# P-Channel 40 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY				
V <sub>DS</sub> (V)	- 40			
$R_{DS(on)}(\Omega)$ at $V_{GS} = -10 \text{ V}$	0.083			
$R_{DS(on)}(\Omega)$ at $V_{GS} = -4.5 V$	0.110			
I <sub>D</sub> (A)	- 3.6			
Configuration	Single			

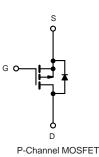


#### **FEATURES**

- Halogen-free According to IEC 61249-2-21
  Definition
- TrenchFET<sup>®</sup> Power MOSFET
- AEC-Q101 Qualified<sup>c</sup>
- 100 %  $R_{\rm q}$  and UIS Tested
- Compliant to RoHS Directive 2002/95/EC



RoHS COMPLIANT HALOGEN FREE



ORDERING INFORMATION	
Package	SOT-23
Lead (Pb)-free and Halogen-free	DTS4501

ABSOLUTE MAXIMUM RATINGS (T <sub>C</sub>	= 25 °C, unles	s otherwise noted	l)	
PARAMETER		SYMBOL	LIMIT	UNIT
Drain-Source Voltage		V <sub>DS</sub>	- 40	V
Gate-Source Voltage		V <sub>GS</sub>	± 20	v
Continuous Drain Current	T <sub>C</sub> = 25 °C	- I <sub>D</sub> -	- 3.6	
	T <sub>C</sub> = 125 °C		- 2.6	
Continuous Source Current (Diode Conduction)		I <sub>S</sub>	- 3.6	А
Pulsed Drain Current <sup>a</sup>		I <sub>DM</sub>	- 18	
Single Pulse Avalanche Current	L = 0.1 mH	I <sub>AS</sub>	- 12	
Single Pulse Avalanche Energy		E <sub>AS</sub>	7.2	mJ
Maximum Power Dissipation <sup>a</sup>	T <sub>C</sub> = 25 °C	PD	3	w
	T <sub>C</sub> = 125 °C	гD	1	٧٧
Operating Junction and Storage Temperature Range	ge	T <sub>J</sub> , T <sub>stg</sub>	- 55 to + 175	C°

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-Ambient	PCB Mount <sup>b</sup>	R <sub>thJA</sub>	166	°C/W	
Junction-to-Foot (Drain)		R <sub>thJF</sub>	50	0/10	

Notes

- a. Pulse test; pulse width  $\leq 300~\mu s,~duty~cycle \leq 2~\%.$
- b. When mounted on 1" square PCB (FR-4 material).
- c. Parametric verification ongoing.

# DTS4501

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<b>SPECIFICATIONS</b> ( $T_C = 25 \ ^{\circ}C_{,*}$	unless otherv	wise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static		•					
Drain-Source Breakdown Voltage	V <sub>DS</sub>	$V_{GS} = 0, I_D = -250 \ \mu A$		- 40	-	-	v
Gate-Source Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =	V <sub>GS</sub> , I <sub>D</sub> = - 250 μA	- 1.5	- 2.0	- 2.5	v
Gate-Source Leakage	I <sub>GSS</sub>	V <sub>DS</sub> =	0 V, $V_{GS}$ = ± 20 V	-	-	± 100	nA
		$V_{GS} = 0 V$	V <sub>DS</sub> = - 40 V	-	-	- 1	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{GS} = 0 V$	$V_{DS}$ = - 40 V, $T_J$ = 125 °C	-	-	- 50	μA
		$V_{GS} = 0 V$	$V_{DS}$ = - 40 V, $T_{J}$ = 175 °C	-	-	- 150	1
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	V <sub>GS</sub> = - 10 V	$V_{DS} \le -5 V$	- 10	-	-	Α
Drain-Source On-State Resistance <sup>a</sup>		$V_{GS} = -10 V$	I <sub>D</sub> = - 3 A	-	0.071	0.083	Ω
	Б	V <sub>GS</sub> = - 10 V	I <sub>D</sub> = - 3 A, T <sub>J</sub> = 125 °C	-	-	0.116	
	R <sub>DS(on)</sub>	$V_{GS} = -10 V$	I <sub>D</sub> = - 3 A, T <sub>J</sub> = 175 °C	-	-	0.139	
		$V_{GS} = -4.5 V$	I <sub>D</sub> = - 2.4 A	-	0.100	0.110	
Forward Transconductanceb	9 <sub>fs</sub>	V <sub>DS</sub> = - 5 V, I <sub>D</sub> = - 3 A		-	8	-	S
Dynamic <sup>b</sup>							
Input Capacitance	C <sub>iss</sub>			-	493	620	
Output Capacitance	C <sub>oss</sub>	$V_{GS} = 0 V$	V <sub>DS</sub> = - 25 V, f = 1 MHz	-	76	95	pF
Reverse Transfer Capacitance	C <sub>rss</sub>			-	51	65	
Total Gate Charge <sup>c</sup>	Qg			-	10.5	16	
Gate-Source Charge <sup>c</sup>	Q <sub>gs</sub>	V <sub>GS</sub> = - 10 V	$V_{DS} = -20 V, I_{D} = -3 A$	-	1.8	-	nC
Gate-Drain Charge <sup>c</sup>	Q <sub>gd</sub>			-	2.6	-	
Gate Resistance	Rg		f = 1 MHz	5	10	15	Ω
Turn-On Delay Time <sup>c</sup>	t <sub>d(on)</sub>			-	5	8	
Rise Time <sup>c</sup>	t <sub>r</sub>	$V_{DD}$ = - 20 V, R <sub>L</sub> = 6.7 $\Omega$ I <sub>D</sub> $\cong$ - 3 A, V <sub>GEN</sub> = - 10 V, R <sub>g</sub> = 1 $\Omega$		-	11	17	- ns
Turn-Off Delay Time <sup>c</sup>	t <sub>d(off)</sub>			-	19	29	
Fall Time <sup>c</sup>	t <sub>f</sub>			-	8	12	
Source-Drain Diode Ratings and Char	acteristics <sup>b</sup>						
Pulsed Current <sup>a</sup>	I <sub>SM</sub>			-	-	- 18	Α
Forward Voltage	V <sub>SD</sub>	I <sub>F</sub> =	- 1.5 A, V <sub>GS</sub> = 0	-	- 0.8	- 1.2	V

Notes

a. Pulse test; pulse width  $\leq$  300  $\mu s,$  duty cycle  $\leq$  2 %.

b. Guaranteed by design, not subject to production testing.

c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



20

16

12

8

4

0

2.0

1.6

1.2

0.8

0.4

0.0

1.0

0.8

0.6

0.4

0.2

0.0

0

 $R_{DS(on)}$  - On-Resistance ( $\Omega$ )

0

I<sub>D</sub> - Drain Current (A)

0

2

= 25 °C

2

4

8

I<sub>D</sub> - Drain Current (A)

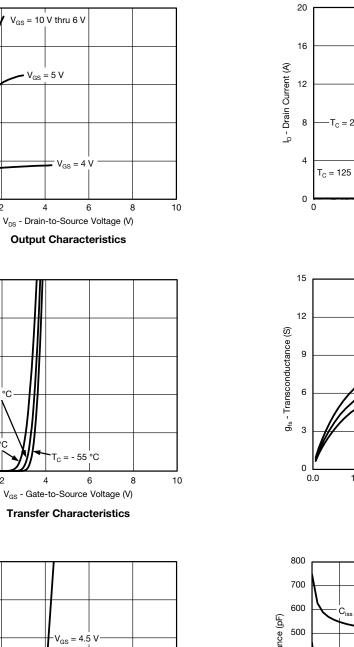
**On-Resistance vs. Drain Current** 

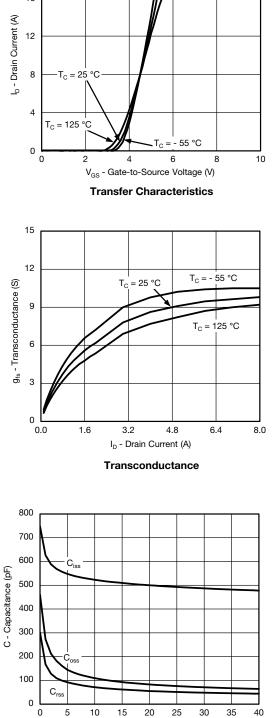
12

T<sub>C</sub> = 125 °C

I<sub>D</sub> - Drain Current (A)

### **TYPICAL CHARACTERISTICS** ( $T_A = 25 \text{ °C}$ , unless otherwise noted)





V<sub>DS</sub> - Drain-to-Source Voltage (V)

Capacitance

 $V_{GS} = 10 V$ 

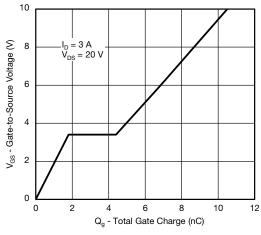
16

20

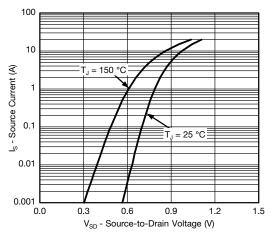


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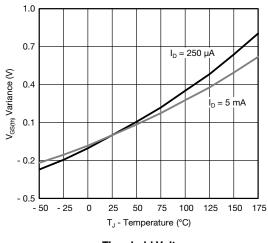
### **TYPICAL CHARACTERISTICS** ( $T_A = 25 \text{ °C}$ , unless otherwise noted)



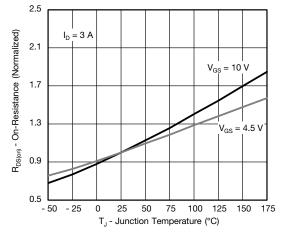
Gate Charge



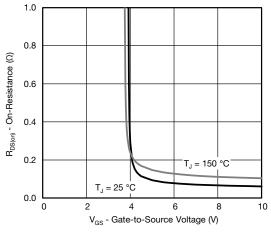
Source Drain Diode Forward Voltage



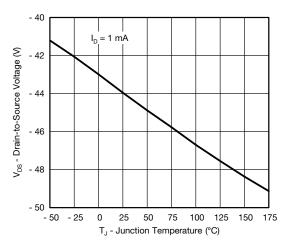
**Threshold Voltage** 



**On-Resistance vs. Junction Temperature** 

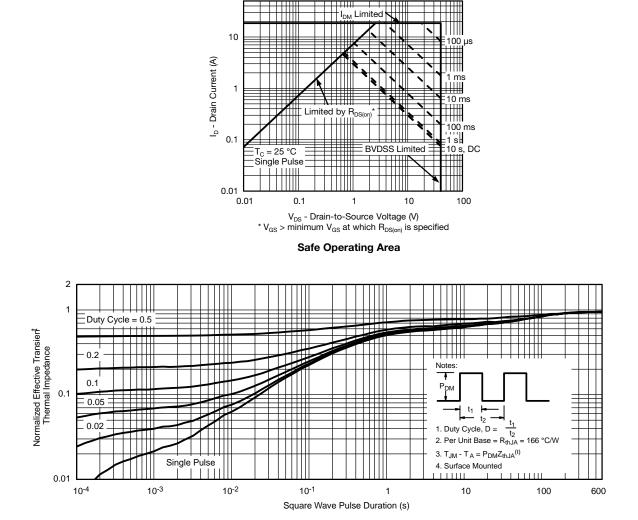


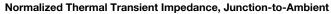
On-Resistance vs. Gate-to-Source Voltage



Drain Source Breakdown vs. Junction Temperature

### **THERMAL RATINGS** ( $T_A = 25 \text{ °C}$ , unless otherwise noted)

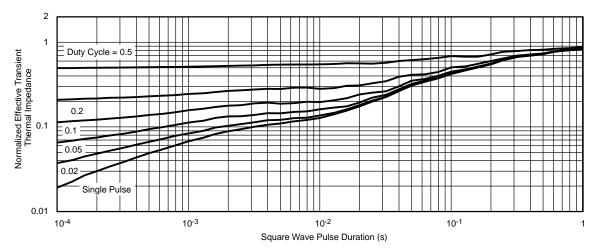






### **THERMAL RATINGS** ( $T_A$ = 25 °C, unless otherwise noted)

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#### Normalized Thermal Transient Impedance, Junction-to-Ambient

#### Note

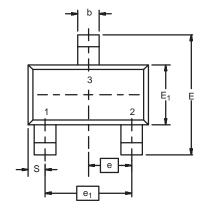
- · The characteristics shown in the two graphs
  - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)

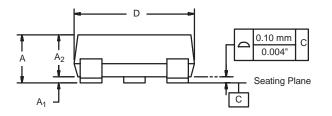
- Normalized Transient Thermal Impedance Junction-to-Foot (25 C)

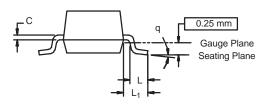
are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.



### SOT-23 (TO-236): 3-LEAD



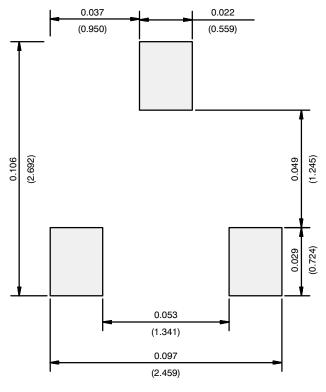




Dim	MILLIM	ETERS	INCHES		
	Min	Max	Min	Max	
Α	0.89	1.12	0.035	0.044	
A <sub>1</sub>	0.01	0.10	0.0004	0.004	
A <sub>2</sub>	0.88	1.02	0.0346	0.040	
b	0.35	0.50	0.014	0.020	
С	0.085	0.18	0.003	0.007	
D	2.80	3.04	0.110	0.120	
E	2.10	2.64	0.083	0.104	
E <sub>1</sub>	1.20	1.40	0.047	0.055	
е	0.95 BSC		0.0374 Ref		
e <sub>1</sub>	1.90 BSC		0.0748 Ref		
L	0.40	0.60	0.016	0.024	
L <sub>1</sub>	0.64 Ref		0.025 Ref		
S	0.50 Ref		0.020 Ref		
q	3°	8°	3°	8°	



#### **RECOMMENDED MINIMUM PADS FOR SOT-23**



**Recommended Minimum Pads** Dimensions in Inches/(mm)

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